# RICOH

# R1525x Series

## 200 mA 42 V Ultra Low Supply Current Voltage Regulator

NO. EA-520-180822

#### OVERVIEW

The R1525x is a low supply current voltage regulator featuring 200mA output current and up to 42 V input voltage. By providing excellent noise immunity, this device is suitable for the power source for control unit used under the electromagnetic environment.

#### **KEY BENEFITS**

- Achieves low-supply current of 2.2μA (Typ.) with the LDO at maximum rating 50 V (Peak Inrush Voltage: 60 V).
- Ensures the design margin by the output voltage with high-accuracy of ±0.6% (Ta=25°C).
- Protects the output voltage variations in high-frequency noise band (10MHz to 1GHz).

#### KEY SPECIFICATIONS

- Input Voltage Range: 3.5 V to 42.0 V
- Maximum Rating: 50 V

(Peak Inrush Voltage: 60 V@200ms or less)

- Operating Temperature Range: −40°C to 105°C
- Supply Current: Typ. 2.2 μA (Typ. 0.1 μA at Standby)
- Dropout Voltage: Typ. 0.6 V (lout = 200 mA, Vout = 5.0 V)
- Output Voltage Range: 1.8 V, 2.5 V, 2.8 V, 3.0 V, 3.3 V, 3.4 V,
   5.0 V, 5.5 V, 6.0 V, 6.4 V, 7.5 V, 8.0 V, 8.5 V, 9.0 V

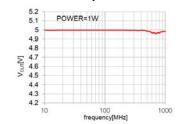
• Output Voltage Accuracy: ±0.6% (Ta = 25°C)

 $\pm 1.6\% (-40^{\circ}\text{C} \le \text{Ta} \le 105^{\circ}\text{C})$ 

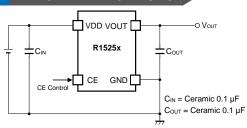
- Input Stability: Typ. 0.01%/V (V<sub>SET</sub> + 1 V ≤ V<sub>IN</sub> ≤ 42 V)
- Short-circuit Protection: Limited to Typ. 80 mA
- Overcurrent Protection: Limited to Typ. 350 mA
- Thermal Shutdown: Detected at Typ.160°C

#### **CHRACTERISTICS**

#### Noise Immunity Characteristic



#### TYPICAL APPLICATIONS



#### **PACKAGES (unit: mm)**



**SOT-23-5** 2.9 x 2.8 x 1.1



**SOT-89-5** 4.5 x 4.35 x 1.5



**HSOP-6J** 5.02 x 6.0 x 1.5



**HSOP-8E** 5.2 x 6.2 x 1.45

#### **APPLICATIONS**

- Power source for home appliances such as refrigerators, rice cookers, and electric hot-water pot.
- Power source for notebook PCs, digital TVs, cordless phones, and private LAN system.
- Power source for office equipment machines such as copiers, printers, facsimiles, scanners, and projectors.

## R1525x

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## **SELECTION GUIDE**

The set output voltage, the package type, and the quality class are user-selectable.

#### **Selection Guide**

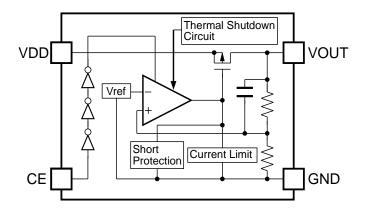
Product Name	Name Package Quantity per Reel		Pb Free	Halogen Free	
R1525NxxxB-TR-FE	SOT-23-5	3,000 pcs	Yes	Yes	
R1525HxxxB-T1-FE	SOT-89-5	1,000 pcs	Yes	Yes	
R1525SxxxB-E2-FE	HSOP-6J	1,000 pcs	Yes	Yes	
R1525SxxxH-E2-FE	HSOP-8E	1,000 pcs	Yes	Yes	

xxx : Specify the set output voltage (Vset)

1.8 V (018) / 2.5 V (025) / 2.8 V (028) / 3.0 V (030) / 3.3 V (033) / 3.4 V (034) / 5.0 V (050) /

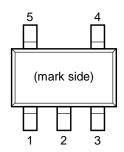
5.5 V (055) / 6.0 V (060) / 6.4 V (064) / 7.5 V (075) / 8.0 V (080) / 8.5 V (085) / 9.0 V (090)

## **BLOCK DIAGRAM**

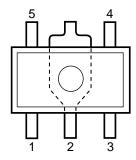


R1525x Block Diagram

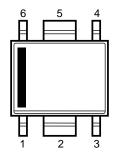
## PIN DESCRIPTIONS



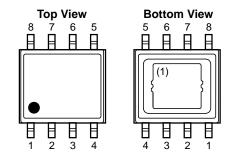
R1525N (SOT-23-5) Pin Configuration



R1525H (SOT-89-5) Pin Configuration



R1525S (HSOP-6J) Pin Configuration



R1525S (HSOP-8E) Pin Configuration

#### **R1525N Pin Description**

Pin No.	Pin Name	Description
1	GND <sup>(2)</sup>	Ground Pin
2	GND <sup>(2)</sup>	Ground Pin
3	CE	Chip Enable Pin (Active-high)
4	VOUT	Output Pin
5	VDD	Input Pin

#### **R1525H Pin Description**

Pin No.	Pin Name	Description
1	VOUT	Output Pin
2	GND <sup>(2)</sup>	Ground Pin
3	CE	Chip Enable Pin (Active-high)
4	GND <sup>(2)</sup>	Ground Pin
5	VDD	Input Pin

<sup>(1)</sup> The tab on the bottom of the package enhances thermal performance and is electrically connected to GND (substrate level). It is recommended that the tab be connected to the ground plane on the board, or otherwise be left open.

<sup>(2)</sup> The GND pin must be wired together when it is mounted on board.

## R1525x

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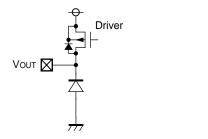
## R1525S (HSOP-6J) Pin Description

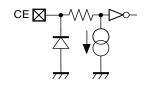
Pin No.	Pin Name	Description
1	VOUT	Output Pin
2	GND <sup>(1)</sup>	Ground Pin
3	CE	Chip Enable Pin (Active-high)
4	GND <sup>(1)</sup>	Ground Pin
5	GND <sup>(1)</sup>	Ground Pin
6	VDD	Input Pin

## R1525S (HSOP-8E) Pin Description

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Pin No.	Pin Name	Description
1	VOUT	Output Pin
2	NC	No Connection
3	NC	No Connection
4	CE	Chip Enable Pin (Active-high)
5	GND	Ground Pin
6	NC	No Connection
7	NC	No Connection
8	VDD	Input Pin

## **Pin Equivalent Circuit Diagrams**





**VOUT Pin Equivalent Circuit Diagram** 

**CE Pin Equivalent Circuit Diagram** 

<sup>&</sup>lt;sup>(1)</sup> The GND pins are connected to each other on the board.

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## **ABSOLUTE MAXIMUM RATINGS**

**Absolute Maximum Ratings** 

Symbol	Parameter	Rating	Unit		
Vin	Input Voltage		-0.3 to 50	V	
Vin	Peak Inrush Voltage <sup>(1)</sup>		60	V	
Vce	CE Pin Input Voltage		-0.3 to 50	V	
V <sub>OUT</sub>	Output Voltage		$-0.3$ to $V_{IN} + 0.3 \le 50$	V	
louт	Output Current		300	mA	
		SOT-23-5	660		
Б	Power Dissipation <sup>(2)</sup>	SOT-89-5	2600	\ \ \ /	
P <sub>D</sub>	(JEDEC STD. 51-7)	HSOP-6J	2700	mW	
		HSOP-8E	2900		
Tj	Junction Temperature		-40 to 125	°C	
Tstg	Storage Temperature Range		-55 to 125	°C	

#### **ABSOLUTE MAXIMUM RATINGS**

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause the permanent damages and may degrade the life time and safety for both device and system using the device in the field. The functional operation at or over these absolute maximum ratings is not assured.

## RECOMMENDED OPERATING CONDITIONS

**Recommended Operating Conditions** 

Symbol	Parameter	Rating	Unit
VIN	Input Voltage	3.5 to 42	V
Та	Operating Temperature Range	−40 to 105	°C

#### **RECOMMENDED OPERATING CONDITIONS**

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if when they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

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<sup>(1)</sup> Duration: 200 ms or less

<sup>(2)</sup> Refer to POWER DISSIPATION for detailed information.

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_	7	-	-,		v

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## **ELECTRICAL CHARACTERISTICS**

 $C_{\text{IN}} = C_{\text{OUT}} = 0.1 \ \mu\text{F}$ , unless otherwise noted. The specifications surrounded by \_\_\_\_\_ are guaranteed by design engineering at  $-40^{\circ}\text{C} \le \text{Ta} \le 105^{\circ}\text{C}$ .

#### **R1525x Electrical Characteristics**

 $(Ta = 25^{\circ}C)$ 

Symbol	Parameter	Condi	tions	Min.	Тур.	Max.	Unit
l	Cupaly Current	V <sub>IN</sub> = 14 V	V <sub>SET</sub> ≤ 5.0 V		2.2	6.5	
Iss	Supply Current	I <sub>OUT</sub> = 0 mA	5.0 V < V <sub>SET</sub>		2.5	6.8	μA
Istandby	Supply Current	V <sub>IN</sub> = 42 V, V <sub>CE</sub> = 0 V			0.1	1.0	μA
Vouт	Output Voltage	V <sub>SET</sub> + 1 V ≤ V <sub>IN</sub> ≤ 42 V	Ta = 25°C	×0.994		×1.006	V
V OUT	Output Voltage	I <sub>OUT</sub> = 1 mA	-40°C ≤ Ta ≤ 105°C	×0.984		×1.016	V
$\Delta V_{\text{OUT}}$	Load Regulation	$V_{IN} = V_{SET} + 3.0 \text{ V}$		Refer	to Prod	uct-spec	cific
$\Delta I_{OUT}$	Load Regulation	1 mA ≤ I <sub>OUT</sub> ≤ 200 mA		Electr	ical Cha	aracteris	tics
$\Delta V_OUT$	Line Degulation	V <sub>SET</sub> + 1 V ≤ V <sub>IN</sub> ≤ 42 V,	V <sub>SET</sub> < 3.3 V	-20	5	20	mV
$\Delta V_{\text{IN}}$	Line Regulation	I <sub>OUT</sub> = 1 mA	3.3 V ≤ V <sub>SET</sub>	-0.02	0.01	0.02	%/V
V <sub>DIF</sub>	Dropout Voltage	louт = 200 mA		Refer to Product-specific			
V DIF	Diopout Voltage	1001 = 200 IIIA		Electr	ical Cha	aracteris	tics
ILIM	Output Current Limit	V <sub>IN</sub> = V <sub>SET</sub> + 3.0 V		220	350	420	mA
Isc	Short-circuit Current	Vout = 0 V		60	80	110	mA
VCEH	CE Input Voltage, high			2.0		42	V
VCEL	CE Input Voltage, low			0		1.0	V
I <sub>PD</sub>	CE Pull-down Current				0.2	0.6	μA
T <sub>TSD</sub>	Thermal Shutdown	Junction Temperature			160		°C
I TSD	Detection Temperature	Junction remperature			100		٥
$T_{TSR}$	Thermal Shutdown	Junction Temperature			135		°C
115K	Release Temperature	Temperature			100		

All parameters are tested under the pulse load condition (Tj  $\approx$  Ta = 25°C).

	R1525x
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The specifications surrounded by	are guaranteed by design engineering at -40°C ≤ Ta ≤ 105°C.

R1525x Product-specific Electrical Characteristics

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(	Та	=	25°	(U

Product	V <sub>OUT</sub> (V)		V <sub>OUT</sub> (V)		ΔV <sub>ουτ</sub> /Δl <sub>ουτ</sub> (mV)		V <sub>DIF</sub> (V)					
Name	(7	$\Gamma a = 25^{\circ}C$	C)	(−40°C	≤ Ta ≤	105°C)				. ,		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	TYP.	MAX.	
R1525x018x	1.7892	1.80	1.8108	1.7712	1.80	1.8288				1.6	2.5	
R1525x025x	2.4850	2.50	2.5150	2.4600	2.50	2.5400						
R1525x028x	2.7832	2.80	2.8168	2.7552	2.80	2.8448				1.2	2.2	
R1525x030x	2.9820	3.00	3.0180	2.9520	3.00	3.0480	-10	10	10 40		İ	
R1525x033x	3.2802	3.30	3.3198	3.2472	3.30	3.3528				0.0	20	
R1525x034x	3.3796	3.40	3.4204	3.3456	3.40	3.4544				0.8	2.0	
R1525x050x	4.9700	5.00	5.0300	4.9200	5.00	5.0800						
R1525x055x	5.4670	5.50	5.5330	5.4120	5.50	5.5880				0.6	4 2	
R1525x060x	5.9640	6.00	6.0360	5.9040	6.00	6.0960			40 50	0.6	1.2	
R1525x064x	6.3616	6.40	6.4384	6.2976	6.40	6.5024	10	10				
R1525x080x	7.9520	8.00	8.0480	7.8720	8.00	8.1280	- <u>-18</u> 18	72				
R1525x085x	8.4490	8.50	8.5510	8.3640	8.50	8.6360				0.5	1.3	
R1525x090x	8.9460	9.00	9.0540	8.8560	9.00	9.1440						

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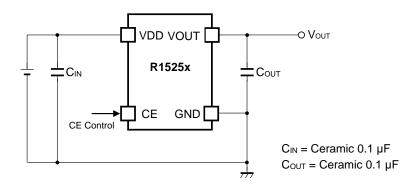
#### THEORY OF OPERATION

#### **Thermal Shutdown**

When the junction temperature of this device exceeds 160°C (Typ.), the built-in thermal shutdown circuit stops the regulator operation. After that, when the temperature drops to 135°C (Typ.) or lower, the regulator restarts the operation. Unless eliminating the overheating problem, the regulator turns on and off repeatedly and a pulse shaped output voltage occurs as result.

#### APPLICATION INFORMATION

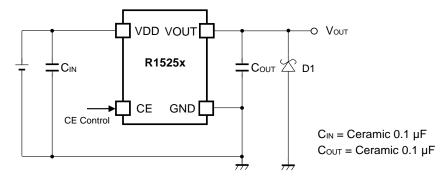
#### **Typical Applications**



**R1525x Typical Applications** 

#### Typical Application for IC Chip Breakdown Prevention

When a sudden surge of electrical current travels along the VOUT pin and GND due to a short-circuit, electrical resonance of a circuit involving an output capacitor and a short circuit inductor generates a negative voltage and may damage the device or the load devices. Connecting a schottky diode (D1) between the VOUT pin and GND has the effect of preventing damage to them.



R1525x Typical Application for IC Chip Breakdown Prevention

#### **TECHNICAL NOTES**

#### **Phase Compensation**

Phase compensation is provided to secure stable operation even when the load current is varied. For this purpose, make sure to use 0.1  $\mu$ F or more of a capacitor ( $C_{OUT}$ ). In case of using a tantalum type capacitor and the ESR (Equivalent Series Resistance) value of the capacitor is large, the output might be unstable. Evaluate the circuit including consideration of frequency characteristics. Connect 0.1  $\mu$ F or more of a capacitor ( $C_{IN}$ ) between  $V_{DD}$  and GND, and as close as possible to the pins.

#### **PCB Layout**

For SOT-23-5 package type, wire the following GND pins together: No. 1 and No. 2 For SOT-89-5 package type, wire the following GND pins together: No. 2 and No. 4. For HSOP-6J package type, wire the following GND pins together: No. 2, No. 4, and No. 5.

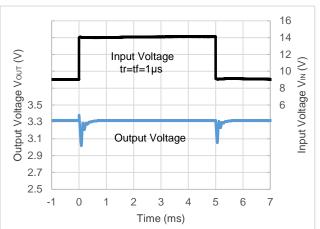
#### Input Transient / Load Transient vs. Output Capacity (Cout)

R1525x performs a stable operation by using 0.1  $\mu$ F of ceramic capacitor as the output capacitor. However, the variation of output voltage may not meet the demand of the system when input voltage and load current vary. In such cases, the variation of output voltage can be minimized significantly by using 10  $\mu$ F or higher ceramic capacitor. When using an electrolytic capacitor for the output line, place the electrolytic capacitor outer side of the ceramic capacitor arranged close to the IC.

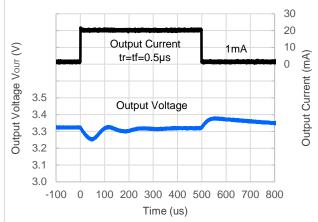
#### <Input Transient Response>

#### <Load Transient Response>

#### R1525x033B



#### R1525x033B

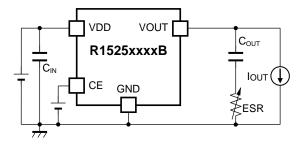


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#### **ESR vs. Output Current**

Using a ceramic type capacitor is recommended for this device, but also other type capacitors having lower ESR can be used. The relation between the output current (I<sub>OUT</sub>) and the ESR of output capacitor is shown below.



 $C_{\text{IN}}$  = Ceramic 0.1  $\mu$ F,  $C_{\text{OUT}}$  = Ceramic 0.1  $\mu$ F

#### **Measurement Conditions**

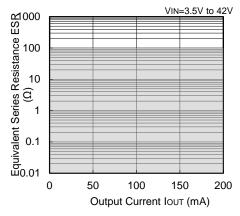
Frequency Band: 10 Hz to 2 MHz

Measurement Temperature: -40°C to 105°C

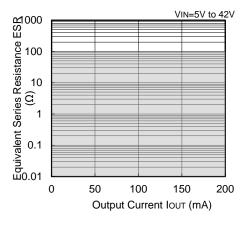
Noise Level in Hatched Area: 40  $\mu V$  (average) or below

Ceramic Capacitors:  $C_{IN} = 0.1~\mu F$ ,  $C_{OUT} = 0.1~\mu F$ 

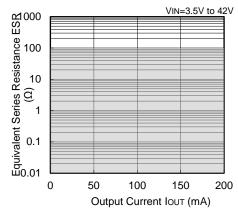
#### R1525x018B



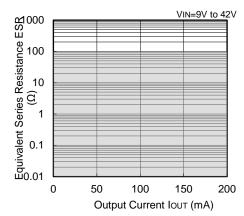
#### R1525x050B



#### R1525x033B



#### R1525x090B



The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51-7.

#### **Measurement Conditions**

Item	Measurement Conditions	
Environment	Mounting on Board (Wind Velocity = 0 m/s)	
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)	
<b>Board Dimensions</b>	76.2 mm × 114.3 mm × 0.8 mm	
Copper Ratio	Outer Layer (First Layer): Less than 95% of 50 mm Square Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square	
Through-holes	Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square φ 0.3 mm × 7 pcs	

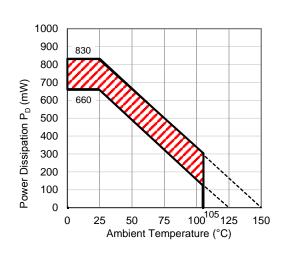
#### **Measurement Result**

 $(Ta = 25^{\circ}C, Tjmax = 125^{\circ}C)$ 

Item	Measurement Result
Power Dissipation	660 mW
Thermal Resistance (θja)	θja = 150°C/W
Thermal Characterization Parameter (ψjt)	ψjt = 51°C/W

θja: Junction-to-Ambient Thermal Resistance

ψjt: Junction-to-Top Thermal Characterization Parameter

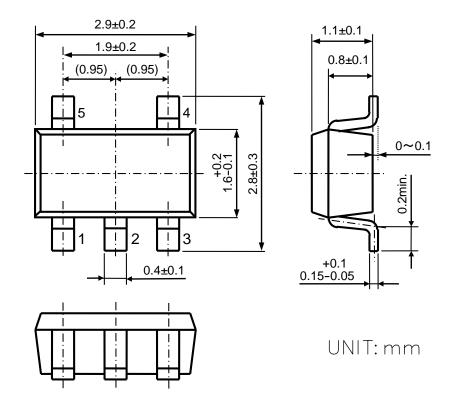


Power Dissipation vs. Ambient Temperature

**Measurement Board Pattern** 

The above graph shows the power dissipation of the package at Tjmax = 125°C and Tjmax = 150°C. Operating the device in the hatched range might have a negative influence on its lifetime. The total hours of use and the total years of use must be limited as follows:

Total Hours of Use	Total Years of Use (4 hours/day)
13,000 hours	9 years



**SOT-23-5 Package Dimensions** 

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51-7.

#### **Measurement Conditions**

Item	Measurement Conditions	
Environment	Mounting on Board (Wind Velocity = 0 m/s)	
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)	
Board Dimensions	76.2 mm × 114.3 mm × 0.8 mm	
	Outer Layer (First Layer): Less than 95% of 50 mm Square	
Copper Ratio	Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square	
	Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square	
Through-holes	φ 0.3 mm × 13 pcs	

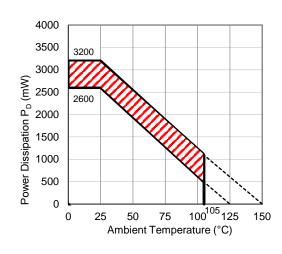
#### **Measurement Result**

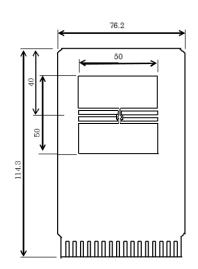
 $(Ta = 25^{\circ}C, Tjmax = 125^{\circ}C)$ 

Item	Measurement Result
Power Dissipation	2600 mW
Thermal Resistance (θja)	θja = 38°C/W
Thermal Characterization Parameter (ψjt)	ψjt = 13°C/W

 $\theta$ ja: Junction-to-Ambient Thermal Resistance

ψjt: Junction-to-Top Thermal Characterization Parameter





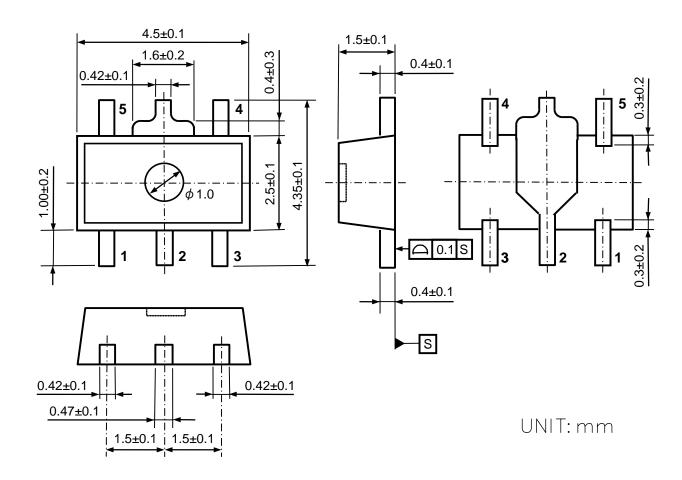
#### Power Dissipation vs. Ambient Temperature

**Measurement Board Pattern** 

The above graph shows the power dissipation of the package at Tjmax = 125°C and Tjmax = 150°C. Operating the device in the hatched range might have a negative influence on its lifetime. The total hours of use and the total years of use must be limited as follows:

Total Hours of Use	Total Years of Use (4 hours/day)
13,000 hours	9 years

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**SOT-89-5 Package Dimensions** 

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51-7.

#### **Measurement Conditions**

Item	Measurement Conditions	
Environment	Mounting on Board (Wind Velocity = 0 m/s)	
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)	
Board Dimensions	76.2 mm × 114.3 mm × 0.8 mm	
	Outer Layer (First Layer): Less than 95% of 50 mm Square	
Copper Ratio	Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square	
	Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square	
Through-holes	φ 0.3 mm × 28 pcs	

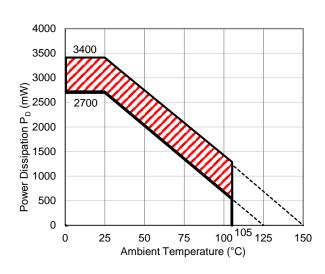
#### **Measurement Result**

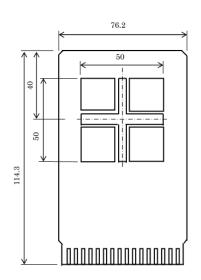
 $(Ta = 25^{\circ}C, Tjmax = 125^{\circ}C)$ 

Item	Measurement Result
Power Dissipation	2700 mW
Thermal Resistance (θja)	θja = 37°C/W
Thermal Characterization Parameter (ψjt)	ψjt = 7°C/W

 $\theta$ ja: Junction-to-Ambient Thermal Resistance

ψjt: Junction-to-Top Thermal Characterization Parameter





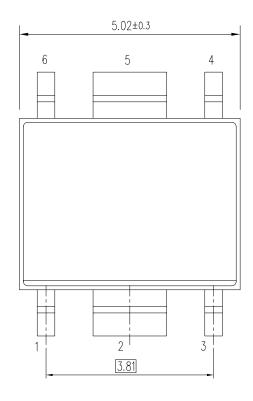
**Power Dissipation vs. Ambient Temperature** 

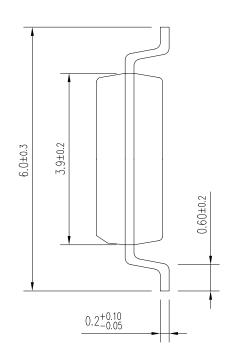
**Measurement Board Pattern** 

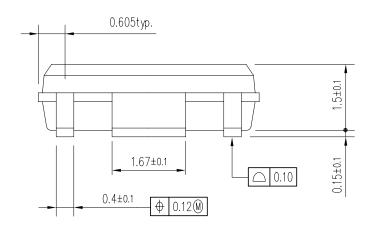
The above graph shows the power dissipation of the package at Tjmax = 125°C and Tjmax = 150°C. Operating the device in the hatched range might have a negative influence on its lifetime. The total hours of use and the total years of use must be limited as follows:

Total Hours of Use	Total Years of Use (4 hours/day)
13,000 hours	9 years

i







UNIT: mm

**HSOP-6J Package Dimensions** 

Ver. B

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51-7.

#### **Measurement Conditions**

	···	
Item	Measurement Conditions	
Environment	Mounting on Board (Wind Velocity = 0 m/s)	
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)	
Board Dimensions	76.2 mm × 114.3 mm × 0.8 mm	
Copper Ratio	Outer Layer (First Layer): Less than 95% of 50 mm Square Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square	
Through-holes	φ 0.3 mm × 21 pcs	

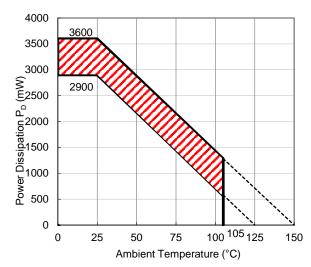
**Measurement Result** 

(Ta = 25°C, Tjmax = 125°C)

Item	Measurement Result
Power Dissipation	2900 mW
Thermal Resistance (θja)	θja = 34.5°C/W
Thermal Characterization Parameter (ψjt)	ψjt = 10 °C/W

 $\theta$ ja: Junction-to-ambient thermal resistance.

ψjt: Junction–to-top of package thermal characterization parameter.



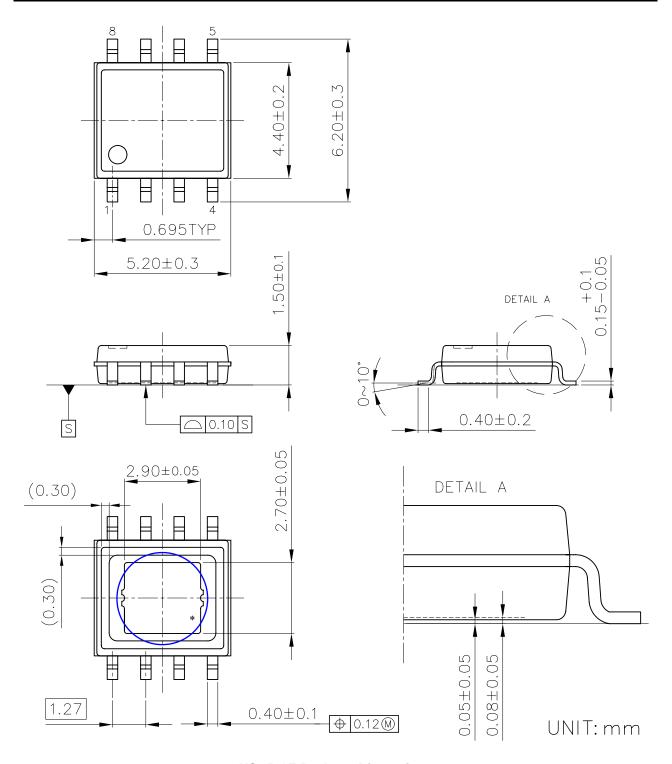
**Power Dissipation vs. Ambient Temperature** 

**Measurement Board Pattern** 

The above graph shows the power dissipation of the package at Tjmax = 125°C and Tjmax = 150°C. Operating the device in the hatched range might have a negative influence on its lifetime. The total hours of use and the total years of use must be limited as follows:

Total Hours of Use	Total Years of Use (4 hours/day)
13,000 hours	9 years

**RICOH** 



**HSOP-8E Package Dimensions** 

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<sup>\*</sup> The tab on the bottom of the package shown by blue circle is substrate potential (GND). It is recommended that this tab be connected to the ground plane on the board but it is possible to leave the tab floating.



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